

IGBT MODULE (S series) 1400V / 35A / PIM



■ Features

- Low $V_{CE(sat)}$
- Compact Package
- P.C. Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit

■ Applications

- Inverter for Motoe Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

■ Maximum ratings and characteristics

● Absolute maximum ratings ($T_c=25^\circ\text{C}$ unless without specified)

Item		Symbol	Condition		Rating	Unit	
Inverter	Collector-Emitter voltage	V _{CES}			1400	V	
	Gate-Emitter voltage	V _{GES}			±20	V	
	Collector current	I _C	Continuous	T _C =25°C	50	A	
				T _C =75°C	35		
		I _{CP}	1ms	T _C =25°C	100	A	
				T _C =75°C	70		
	-I _C			35	A		
Collector power dissipation		P _C	1 device		240	W	
Brake	Collector-Emitter voltage	V _{CES}			1400	V	
	Gate-Emitter voltage	V _{GES}			±20	V	
	Collector current	I _C	Continuous	T _C =25°C	35	A	
				T _C =75°C	25		
		I _{CP}	1ms	T _C =25°C	70	A	
				T _C =75°C	50		
	Collector power dissipation		P _C	1 device		180	W
Repetitive peak reverse voltage		V _{R_{RRM}}			1400	V	
Converter	Repetitive peak reverse voltage		V _{R_{RRM}}		1600	V	
	Average output current		I _O		50Hz/60Hz sine wave	35	A
	Surge current (Non-Repetitive)		I _{FSM}		T _J =150°C, 10ms	360	A
	I ² t (Non-Repetitive)		I ² t		half sine wave	648	A²s
Operating junction temperature		T _J				+150	°C
Storage temperature		T _{stg}				-40 to +125	°C
Isolation voltage	between terminal and copper base *2	V _{iso}	AC : 1 minute		AC 2500		V
	between thermistor and others *3				AC 2500		
Mounting screw torque				3.5 * ₁		N·m	

*1 Recommendable value : 2.5 to 3.5 N·m (M5)

*2 All terminals should be connected together when isolation test will be done.

*3 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

● Electrical characteristics (T_j=25°C unless otherwise specified)

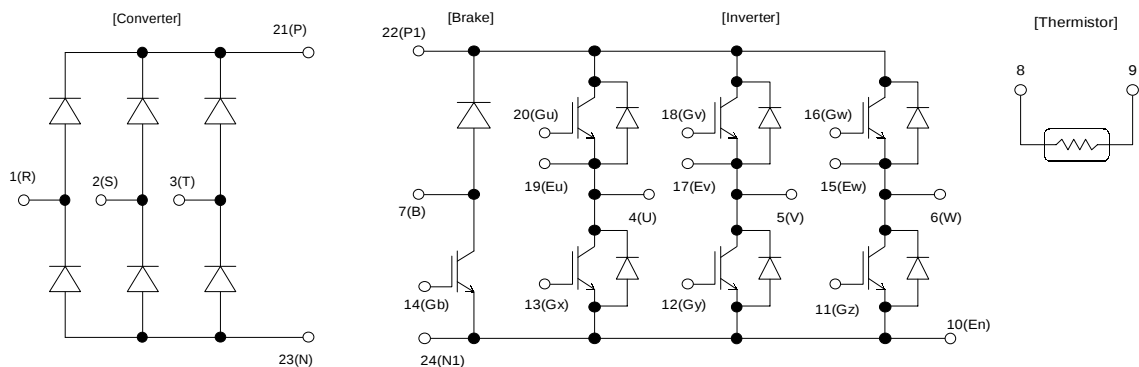
Item		Symbol	Condition	Characteristics			Unit
				Min.	Typ.	Max.	
Inverter	Zero gate voltage collector current	I _{CES}	V _{CE} =1400V, V _{GE} =0V			1.0	mA
	Gate-Emitter leakage current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			0.2	μA
	Gate-Emitter threshold voltage	V _{GE(th)}	V _{CE} =20V, I _C =35mA	5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	V _{CE(sat)}	V _{GE} =15V, I _C =35A chip		2.2		V
			terminal		2.35	2.7	
	Input capacitance	C _{ies}	V _{GE} =0V, V _{CE} =10V, f=1MHz		4200		pF
	Turn-on time	t _{on}	V _{CC} =800V		0.35	1.2	μs
		t _r	I _C =35A		0.25	0.6	
		t _{r(i)}	V _{GE} =±15V		0.1		
	Turn-off	t _{off}	R _G =33Ω		0.45	1.0	
		t _f			0.08	0.3	
	Forward on voltage	V _F	I _F =35A chip		2.4		V
			terminal		2.55	3.4	
Brake	Reverse recovery time of FRD	t _{rr}	I _F =35A			0.35	μs
	Zero gate voltage collector current	I _{CES}	V _{CE} =1400V, V _{GE} =0V			1.0	mA
	Gate-Emitter leakage current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			0.2	μA
	Collector-Emitter saturation voltage	V _{CE(sat)}	I _C =25A, V _{GE} =15V chip		2.2		V
			terminal		2.35	2.8	
	Turn-on time	t _{on}	V _{CC} =800V		0.35	1.2	μs
		t _r	I _C =25A		0.25	0.6	
	Turn-off time	t _{off}	V _{GE} =±15V		0.45	1.0	
		t _f	R _G =51Ω		0.08	0.3	
	Reverse current	I _{RRM}	V _R =1400V			1.0	mA
Converter	Forward on voltage	V _{FM}	I _F =35A chip		1.1		V
			terminal		1.2	1.5	
	Reverse current	I _{RRM}	V _R =1600V			1.0	mA
	Resistance	R	T=25°C		5000		Ω
			T=100°C	465	495	520	
	B value	B	T=25/50°C	3305	3375	3450	K

● Thermal resistance Characteristics

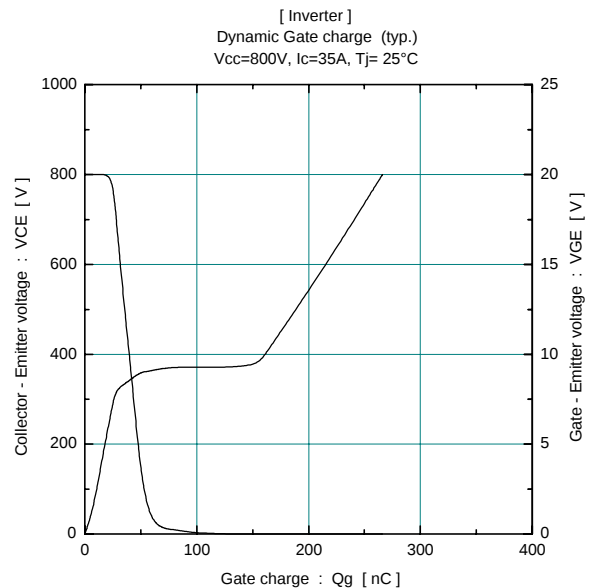
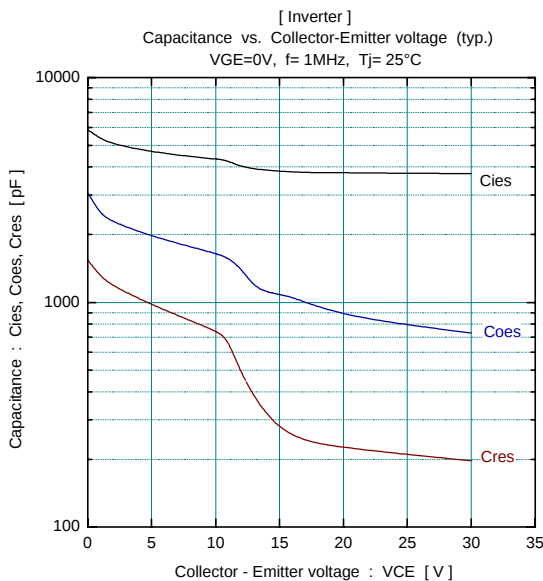
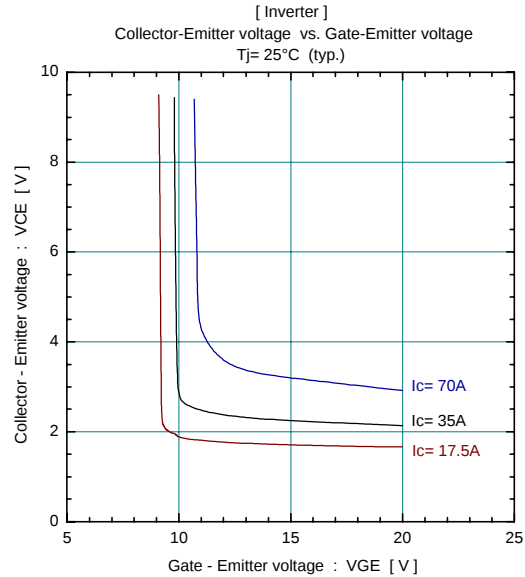
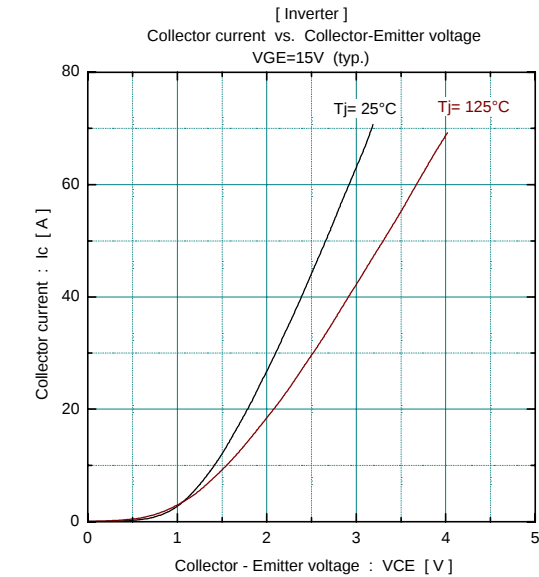
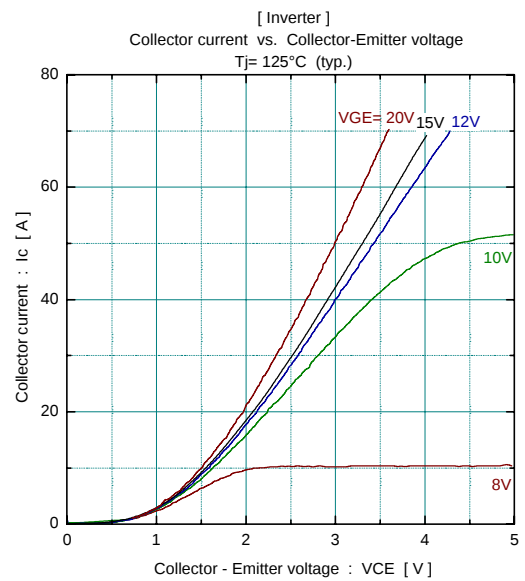
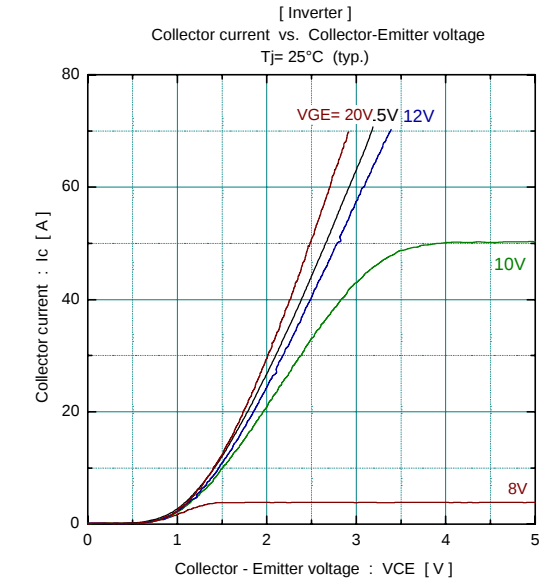
Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance (1 device)	R _{th(j-c)}	Inverter IGBT			0.52	°C/W
		Inverter FWD			0.90	
		Brake IGBT			0.69	
		Converter Diode			0.75	
Contact thermal resistance *	R _{th(c-f)}	With thermal compound		0.05		

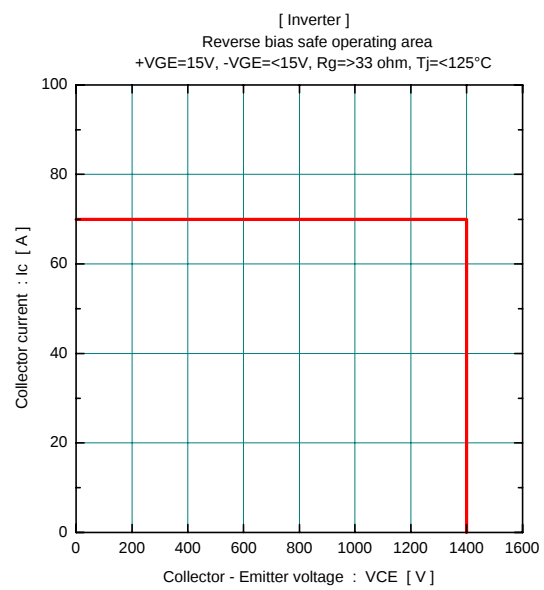
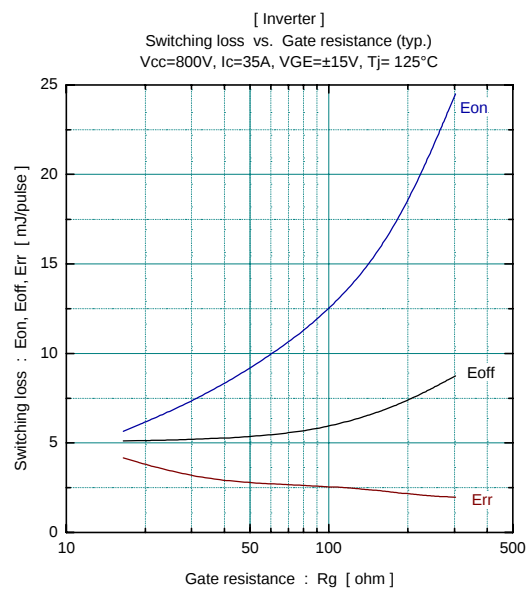
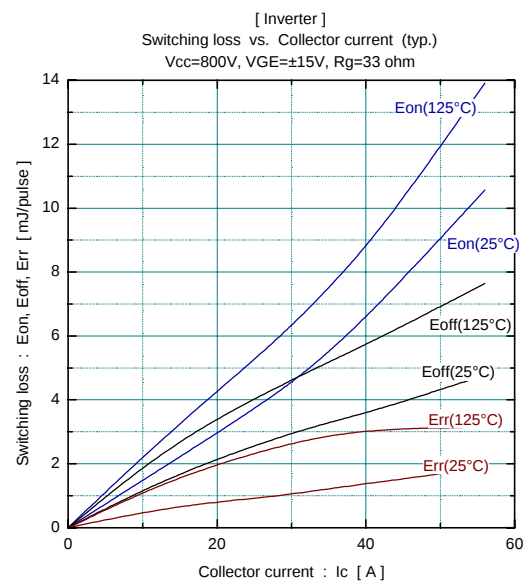
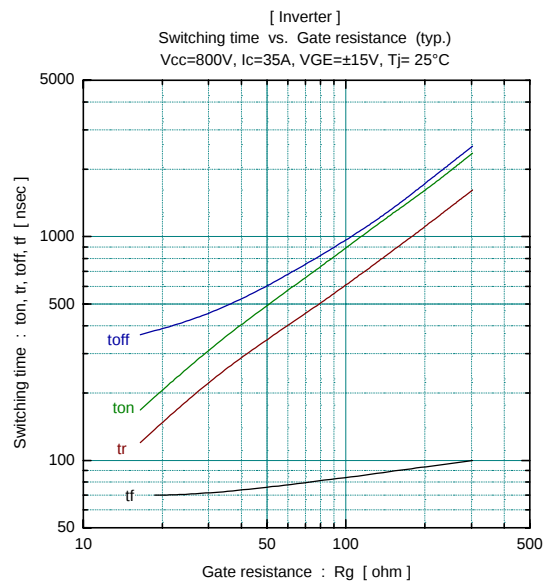
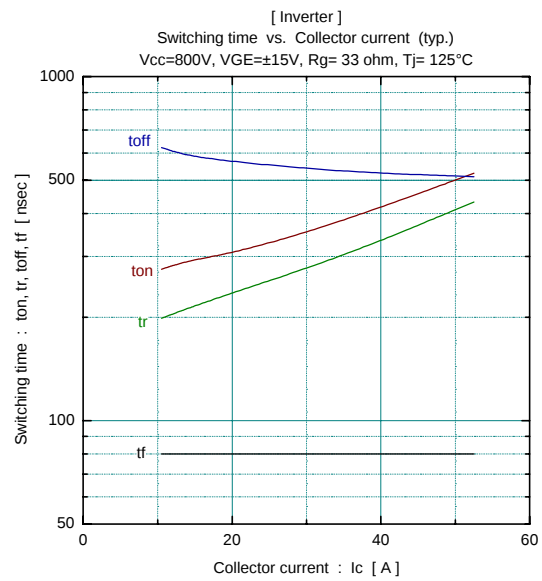
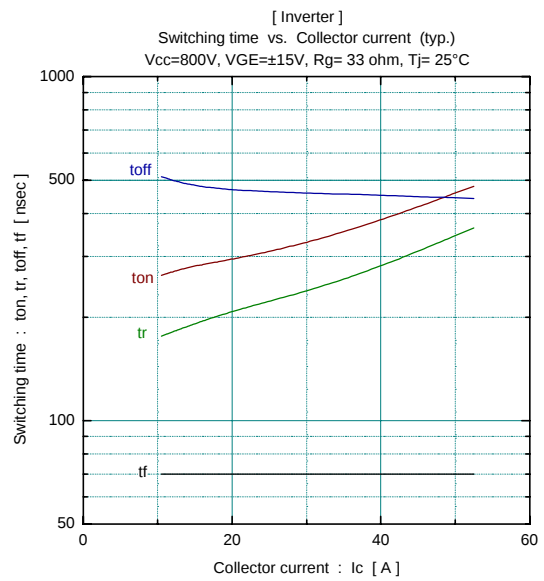
* This is the value which is defined mounting on the additional cooling fin with thermal compound

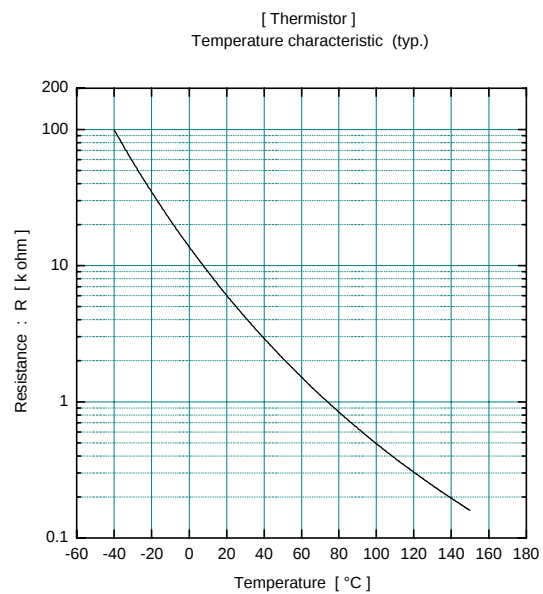
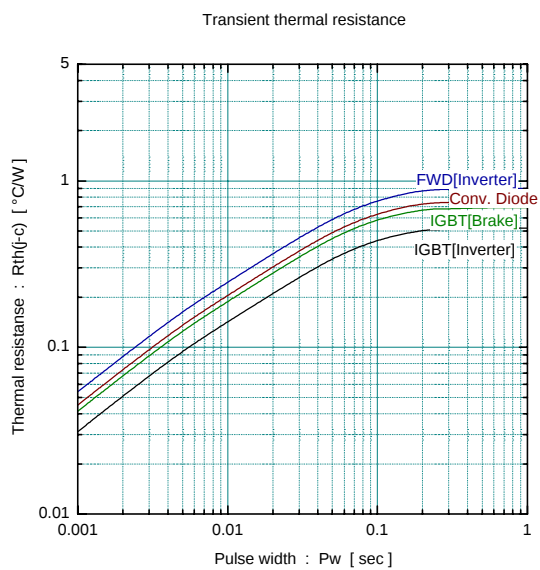
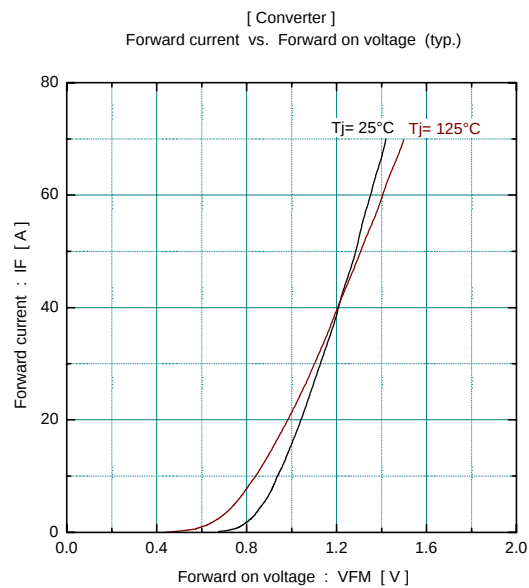
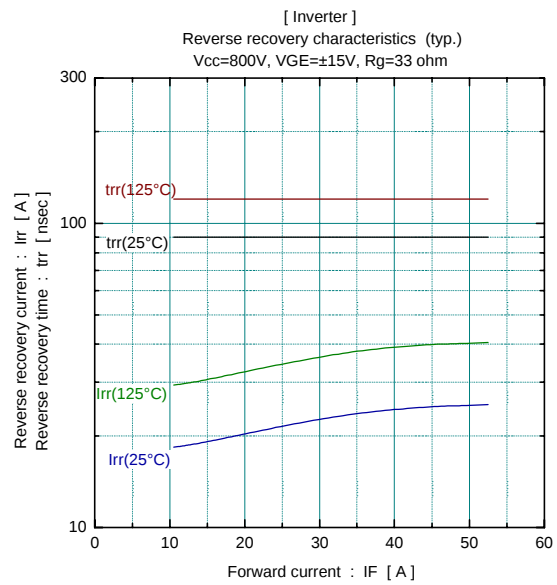
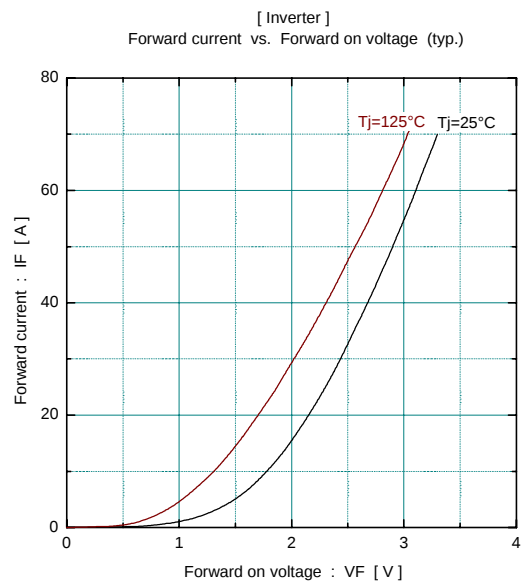
■ Equivalent Circuit Schematic

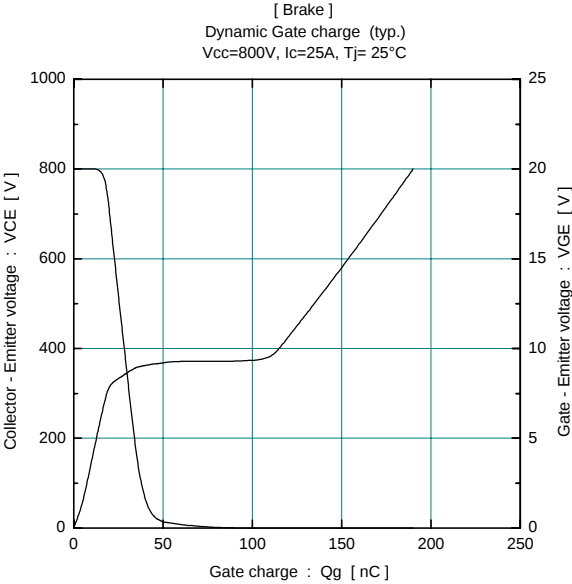
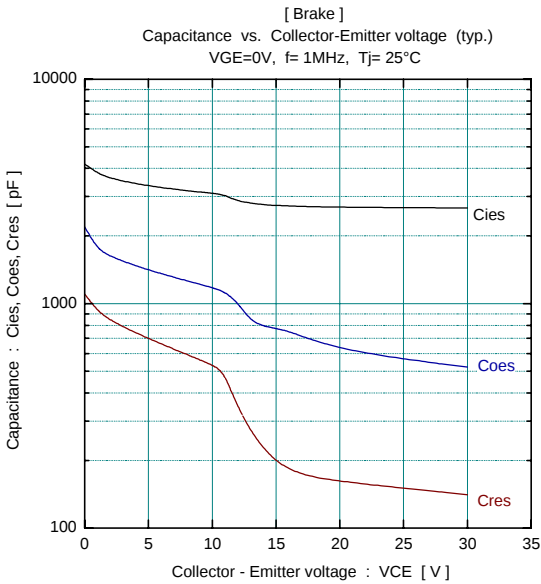
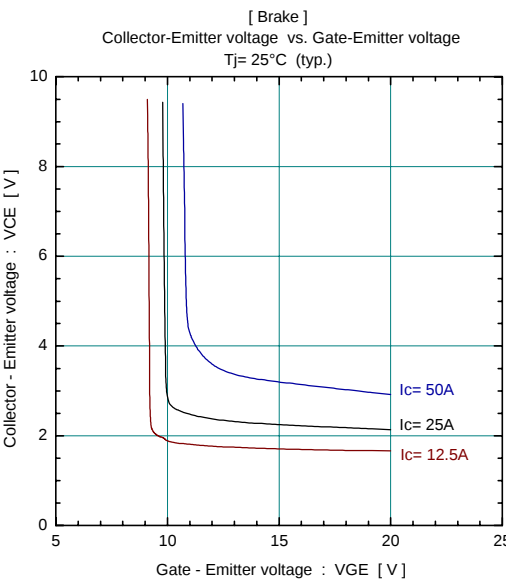
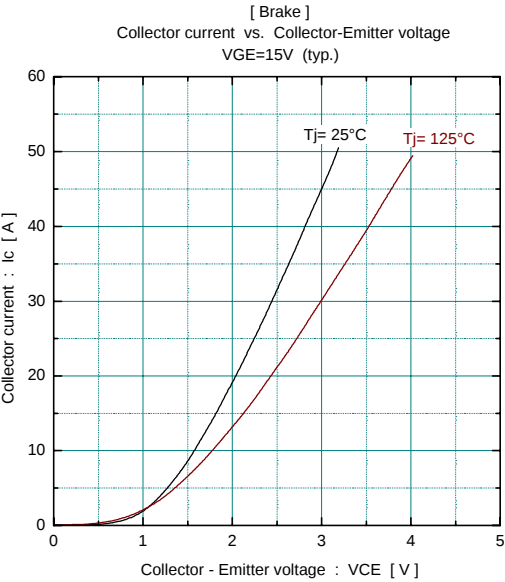
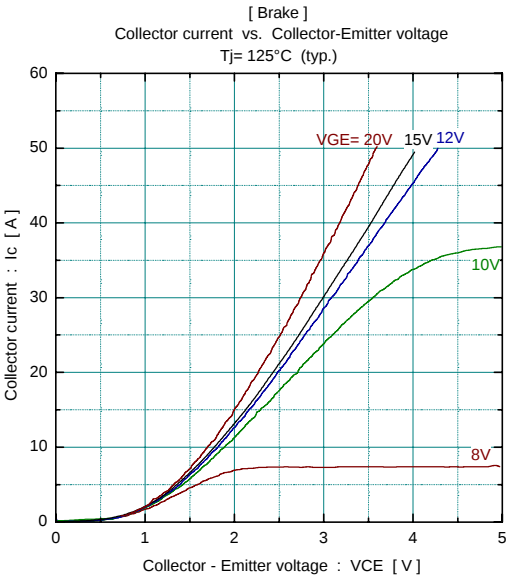
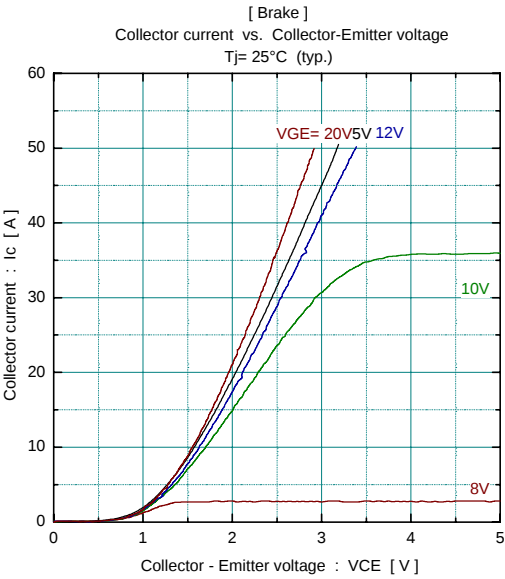


■ Characteristics (Representative)

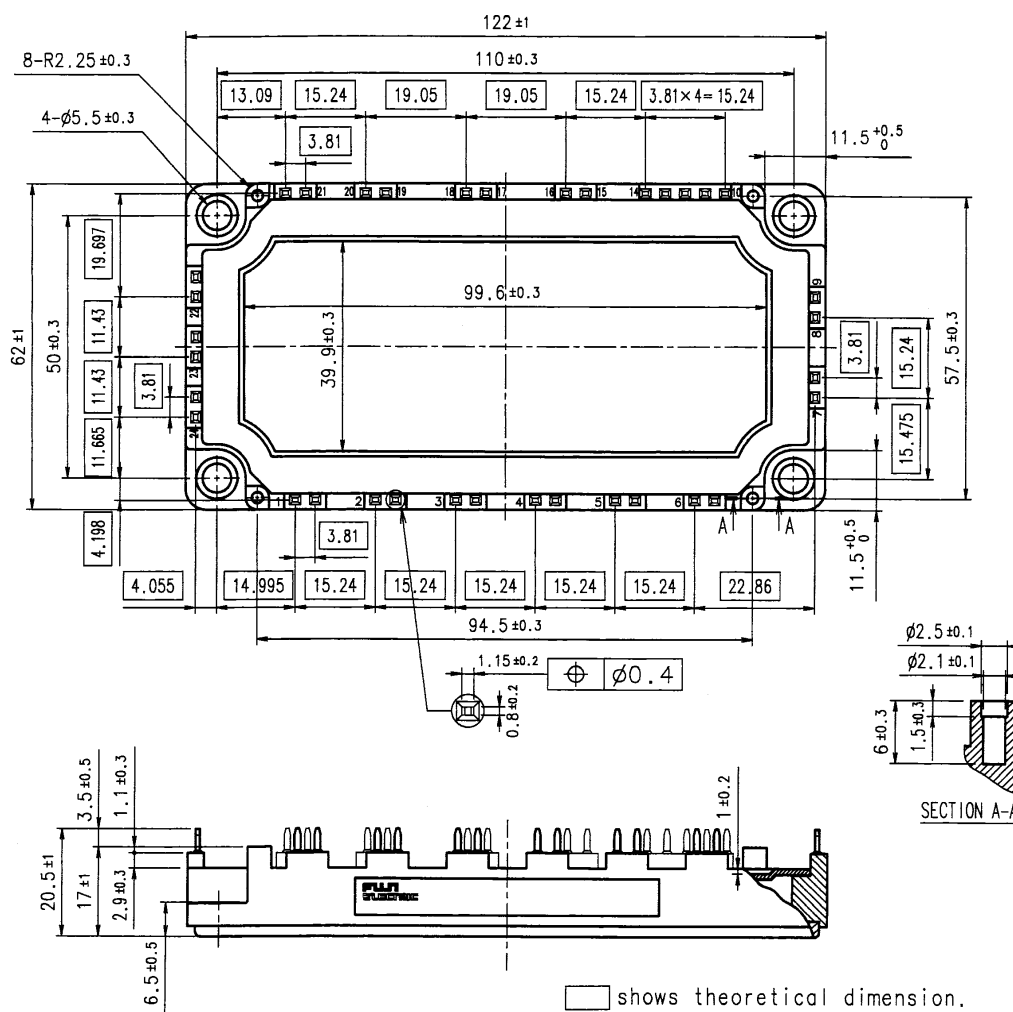








■ Outline Drawings, mm



mass : 260g